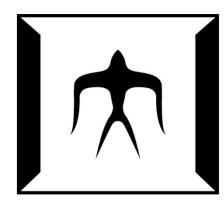
An indirect ammonia synthesis system by using dielectric barrier discharge

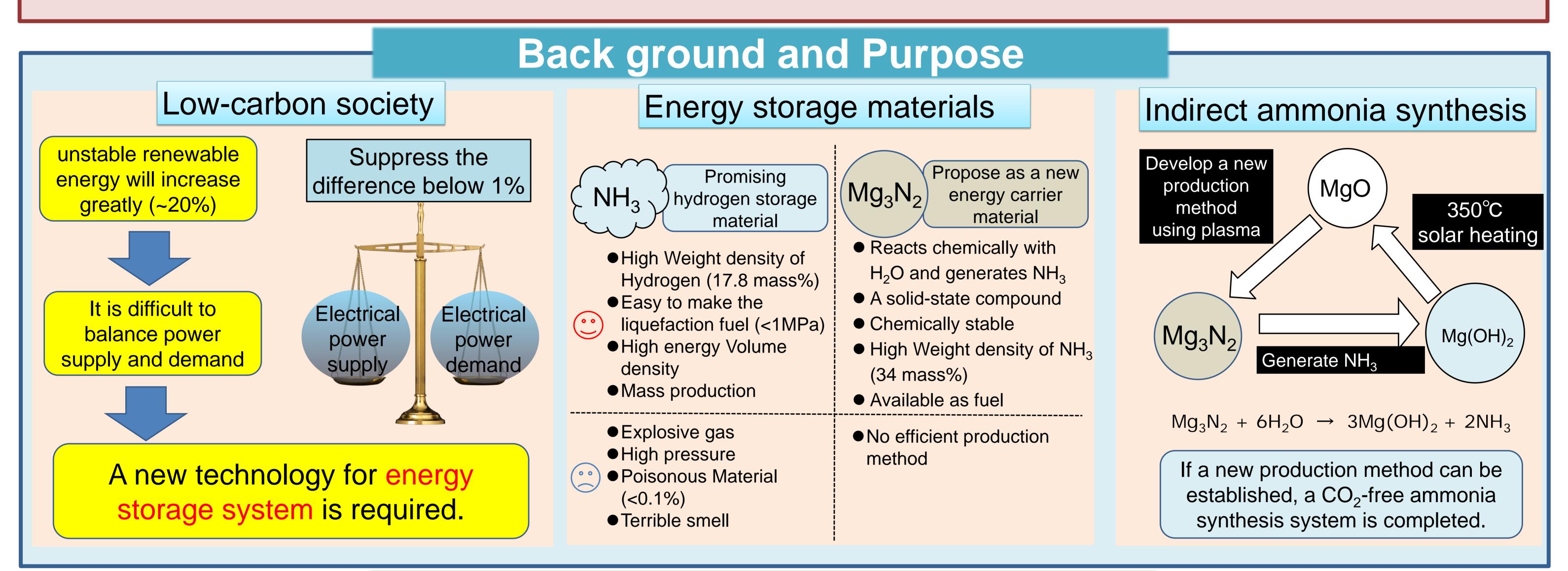
Shungo Zen¹



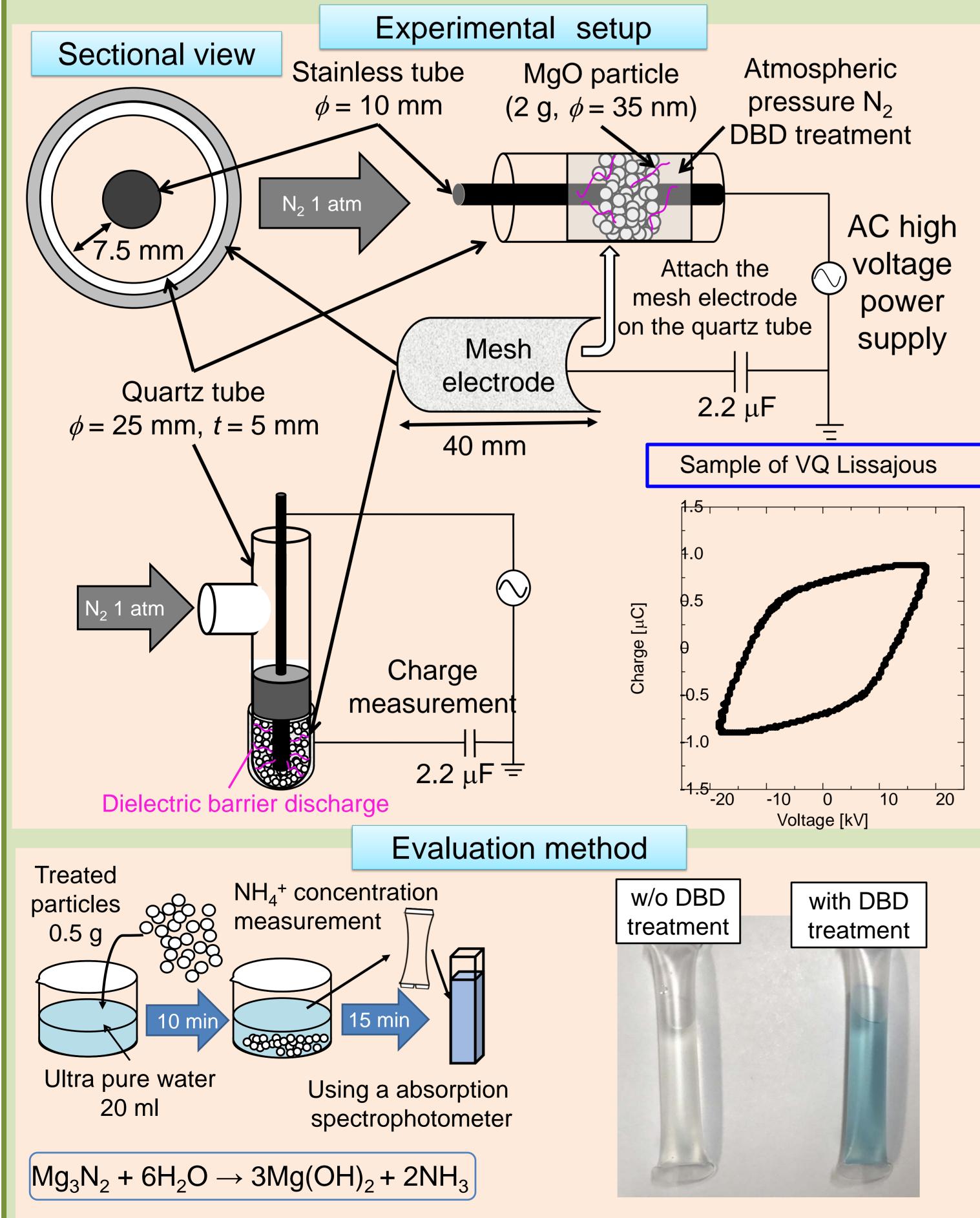
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Summary

An Indirect Ammonia synthesis from nitrogen and water through plasma processing is proposed and demonstrated. NH₃ is a promising hydrogen storage material because of its high hydrogen storage density. Magnesium nitride (Mg₃N₂) is a key material for the indirect NH₃ synthesis because reaction of Mg₃N₂ with water easily generates NH_3 at room temperature. Therefore, in this study, we focused on generation of Mg_3N_2 by nitridation of Magnesium oxide (MgO) with a nonthermal atmospheric-pressure dielectric barrier discharge (DBD) plasma under a N₂ atmosphere. Since NH₃ is generated through a simple chemical reaction, our scheme does not cause NH₃ decomposition by plasma, which is one of the greatest concerns associated with plasma synthesis. Unlike the conventional NH₃ generation process which emits CO₂ and require high temperature and pressure, our scheme enables NH₃ synthesis from N₂ and H₂O without CO₂ emission. This leads to achievement of an on-site small scale NH₃ synthesis system under mild conditions, which is necessary for a future low-carbon society.

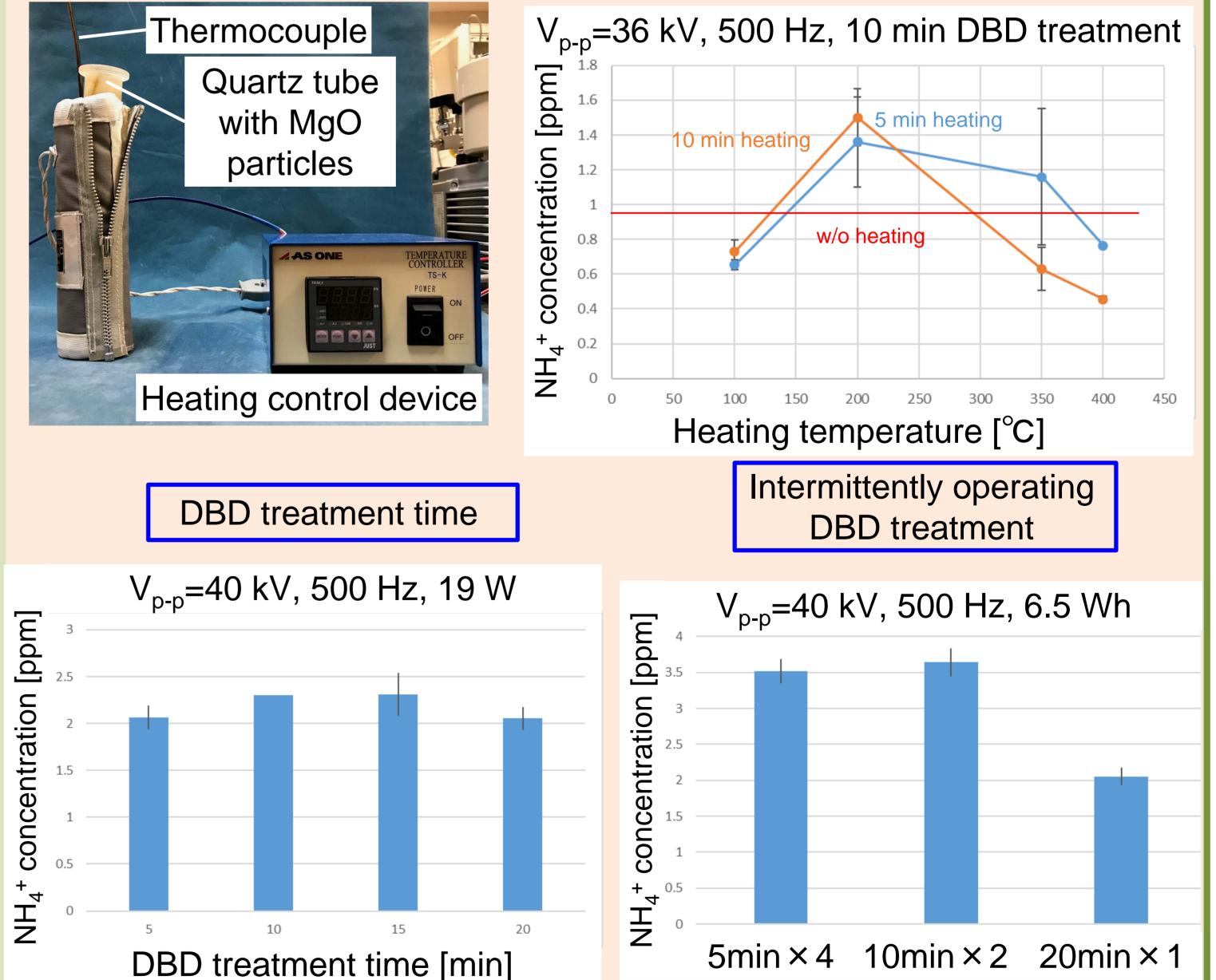


Experimental result and discussion



Results and discussion





Evaluate the production amount of Mg_3N_2 by measuring the NH_4^+ concentration

Atmospheric pressure N₂ DBD treatment can generate Mg₃N₂ from MgO. $3MgO+N_2 \rightarrow Mg_3N_2+1.5O_2 - 1576kJ$

- The production amount of Mg_3N_2 was increasing by preheating treatment.
- Saturated tendency was seen in the production amount of Mg_3N_2 .
- Saturated tendency was able to improve by intermittently operating **DBD** treatment.